MOSPEC

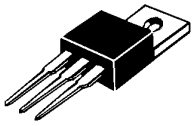
S40M45C

Switchmode Schottky Barrier Power Rectifiers

Using the Schottky Barrier principle with high temperature operation metal. The properitary barrier technology allows for reliable operation up to 150℃ junction temperature. Typical application are in switching Mode Power Supplies such as adaptators, Photovoltaic Solar cell protection,free-wheeling and polarity protection diodes.

SCHOTTKY BARRIER RECTIFIERS

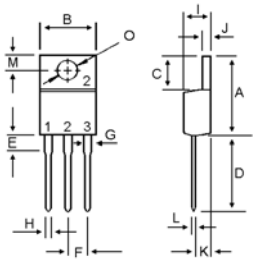
40 AMPERES
45VOLTS



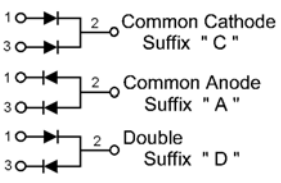
TO-220AB

Features

- ∗Ultra Low Forward Voltage.
- ∗Low Switching noise.
- ∗High Current Capacity
- ∗Low Power Loss & High efficiency.
- ∗150℃ Operating Junction Temperature
- ∗Low Stored Charge Majority Carrier Conduction.
- ∗Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O
- ∗ ESD: 4KV(Min.) Human-Body Model
- ∗*In compliance with EU RoHs 2002/95/EC directives*
- ∗Mounting Torqure: 5 in-lbs.Max.



DIM	MILLIMETERS	
	MIN	MAX
A	14.68	15.32
B	9.78	10.42
C	5.02	6.52
D	13.06	14.62
E	3.57	4.07
F	2.42	2.66
G	1.20	1.47
H	0.72	0.96
I	4.22	4.98
J	1.14	1.38
K	2.20	2.98
L	0.33	0.55
M	2.48	2.98
O	3.70	3.90



MAXIMUM RATINGS

Characteristic	Symbol	S40M45C	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	45	V
RMS Reverse Voltage	$V_{R(RMS)}$	31.5	V
Average Rectifier Forward Current (per diode) Total Device (Rated V_R),	$I_{F(AV)}$	20 40	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I_{FSM}	340	A
Operating and Storage Junction Temperature Range	T_J , T_{stg}	-65 to +150	℃

THERMAL RESISTANCES

Typical Thermal Resistance junction to case(per diode)	$R_{\theta j\text{-}c}$	6.8	℃/w

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	S40M45C			Unit
		Min	Typ.	Max.	
Maximum Instantaneous Forward Voltage (per diode)	V_F				V
(I_F =0.1 Amp T_C = 25℃)		---	0.35	---	
(I_F =20.0 Amp T_C = 25℃)		---	0.52	0.55	
Maximum Instantaneous Reverse Current	I_R				mA
(Rated DC Voltage, T_C = 25℃)		---	0.15	0.18	
(Rated DC Voltage, T_C = 125℃)		---	50	---	

S40M45C

FIG-1 FORWARD CURRENT DERATING CURVE

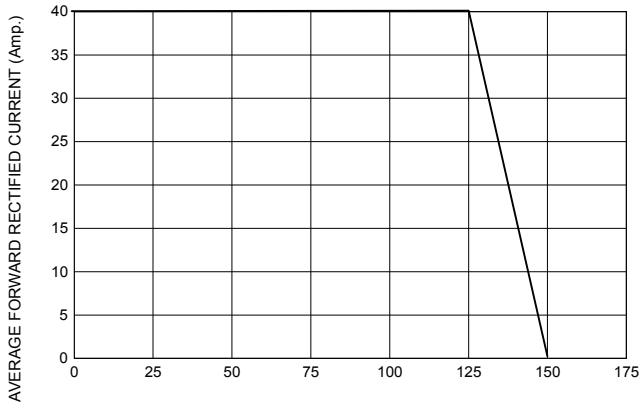


FIG-2 TYPICAL FORWARD CHARACTERISITICS

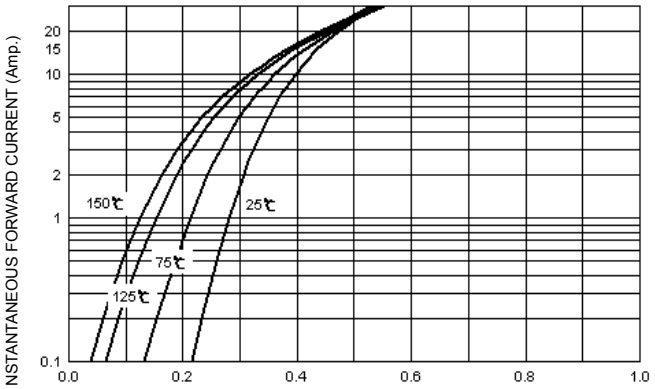


FIG-3 TYPICAL REVERSE CHARACTERISTICS

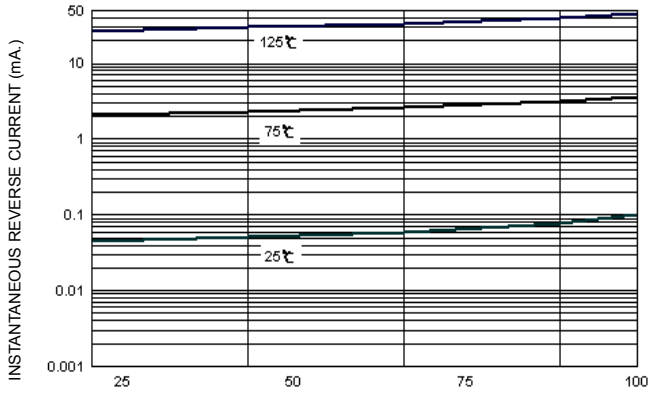


FIG-4 TYPICAL JUNCTION CAPACITANCE

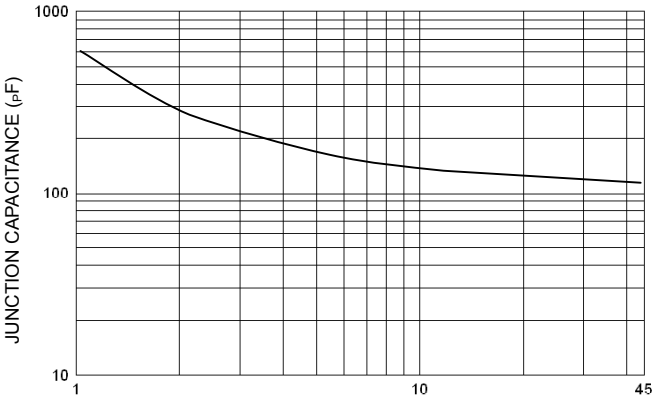
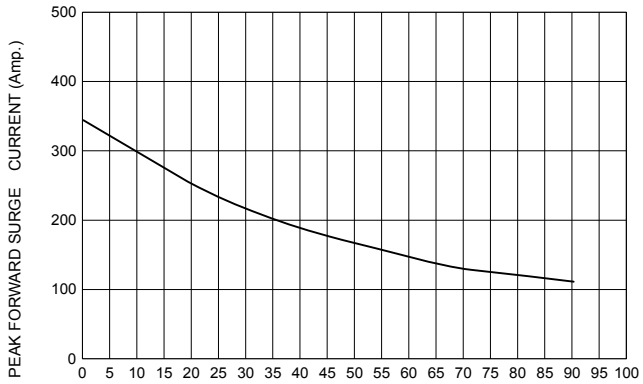


FIG-5 PEAK FORWARD SURGE CURRENT



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